



PATENT  
Customer No. 22,852  
Attorney Docket No. 08409.0047

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: )  
)  
Tuung Luoh et al. ) Group Art Unit: 1765  
)  
Application No.: 10/733,230 ) Examiner: Not yet assigned  
)  
Filed: December 12, 2003 )  
)  
For: ELIMINATION OF THE FAST- )  
ERASE PHENOMENA IN FLASH )  
MEMORY )

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. § 1.97(b)**

Pursuant to 37 C.F.R. §§ 1.56 and 1.97(b), applicants bring to the attention of the Examiner the documents listed on the attached PTO 1449. This Information Disclosure Statement is being filed before the mailing date of a first Office Action on the merits for the above-referenced application.

Applicants respectfully request that the Examiner consider the listed documents and indicate that the documents were considered by making appropriate notations on the attached form.

This submission does not represent that a search has been made or that no better art exists and does not constitute an admission that the listed documents are material or constitute "prior art." If the Examiner applies the documents as prior art

against any claim in the application and applicants determine that the cited documents do not constitute "prior art" under United States law, applicants reserves the right to present to the office the relevant facts and law regarding the appropriate status of such documents.

Applicants further reserve the right to take appropriate action to establish the patentability of the disclosed invention over the listed documents, should any of the documents be applied against the claims of the present application.

If there is any fee due in connection with the filing of this Statement, please charge the fee to our Deposit Account No. 06-0916.

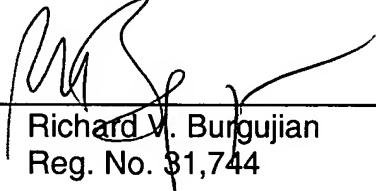
Respectfully submitted,

FINNEGAN, HENDERSON, FARABOW,  
GARRETT & DUNNER, L.L.P.

Dated:

3/31/04

By:

  
Richard W. Burgujian  
Reg. No. 31,744

## INFORMATION DISCLOSURE CITATION

Atty. Docket No. 08409.0047	Serial No. 10/733,230
Applicant Tuung Luoh et al.	
Filing Date December 12, 2003	Group: 1765

## U.S. PATENT DOCUMENTS

Examiner Initials	Document Number	Issue Date	Name	Class	Sub Class	Filing Date If Appropriate
	5,914,896	June 22, 1999	Lee et al.			
	6,381,670	April 30, 2002	Lee et al.			

## FOREIGN PATENT DOCUMENTS

Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or No

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Seiichi Mori et al., "Polyoxide Thinning Limitation and Superior ONO Interpoly Dielectric for Nonvolatile Memory Devices", IEEE TRANSACTIONS ON ELECTRON DEVICES, Vol. 38, No. 2, February 1991, pp. 270-277
	Seiichi Mori et al., "ONO Inter-Poly Dielectric Scaling for Nonvolatile Memory Applications", IEEE TRANSACTIONS ON ELECTRON DEVICES, Vol. 38, No. 2, February 1991, pp. 386-391

Examiner	Date Considered
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	
Form PTO 1449	Patent and Trademark Office - U.S. Department of Commerce